ORGE O. SAILE & ASSOCIATES
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₹S01-133



September 10, 2001

To: Assistant Commissioner of Patents
Office of Initial Patent Examination
Customer Service Contes

Customer Service Center Washington, D.C. 20231

From: Stephen B. Ackerman

Subject:

Serial No.:

09/905,408

Filing Date:

07/16/01

Inventor:

S. H. Chen

Title:

Selective Formation of Metal Gate for Dual Gate Oxide

Application

REQUEST TO CORRECT FILING RECEIPT

Dear Sir:

On the copy of the enclosed Filing Receipt, there are errors in the list of Applicants. The second Applicant's name is misspelled. Mr. Tsai's corrected name and residence reads; Minghsing Tsai, Taipei, Taiwan.

Please make the necessary change to correct the error on the Filing Receipt.

If there are any questions, please contact the undersigned attorney at (845) 452-5863. Thank you for your attention to this matter.

Respectfully Submitted,

Stephen B. Ackerman, Reg. No. 37,761



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ATTY.DOCKET.NO DRAWINGS TOT CLAIMS IND CLAIMS GRP ART UNIT FIL FEE REC'D APPLICATION NUMBER **FILING DATE** 07/16/2001 2812 710 TS01-133 5 14 2 09/905,408

GEORGE O. SAILE 20 MCINTOSH DRIVE

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CONFIRMATION NO. 3764

FILING RECEIPT



2800 MAIL ROOM

Date Mailed: 08/28/2001

Receipt is acknowledged of this nonprovisional Patent Application. It will be considered in its order and you will be notified as to the results of the examination. Be sure to provide the U.S. APPLICATION NUMBER, FILING DATE, NAME OF APPLICANT, and TITLE OF INVENTION when inquiring about this application. Fees transmitted by check or draft are subject to collection. Please verify the accuracy of the data presented on this receipt. If an error is noted on this Filing Receipt, please write to the Office of Initial Patent Examination's Customer Service Center. Please provide a copy of this Filing Receipt with the changes noted thereon. If you received a "Notice to File Missing Parts" for this application, please submit any corrections to this Filing Receipt with your reply to the Notice. When the USPTO processes the reply to the Notice, the USPTO will generate another Filing Receipt incorporating the requested corrections (if appropriate).

Applicant(s)

Sheng Hsiung Chen, Taichung Connty, TAIWAN; Mingh-Sing Tsai, Taipei, TAIWAN;

Assignment For Published Patent Application

Taiwan Semiconductor Manufacturing Company;

Domestic Priority data as claimed by applicant

Foreign Applications

If Required, Foreign Filing License Granted 08/28/2001

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Non-Publication Request: Yes

Early Publication Request: No

Title

Selective formation of metal gate for dual gate oxide application

Preliminary Class

438

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